Product data sheet

1. General description

NPN low V_{CEsat} transistor, encapsulated in an ultra thin SOT1061D (DFN2020D-3) leadless small Surface-Mounted Device (SMD) plastic package with medium power capability and side-wettable flanks (SWF).

2. Features and benefits

- Very low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- High efficiency due to less heat generation
- · High temperature applications up to 175 °C
- · Reduced Printed-Circuit Board (PCB) area requirements
- · Leadless small SMD plastic package with soldarable side pads
- Exposed heat sink for excellent thermal and electrical conductivity
- · Suitable for Automatic Optical Inspection (AOI) of solder joint
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Linear voltage regulation
- Loadswitch
- · Battery-driven devices
- · Power management
- Charging circuits
- Power switches (e.g. motors, fans)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	10	V
I _C	collector current		-	-	3	Α
h _{FE}	DC current gain	V_{CE} = 2 V; I_{C} = 100 mA; pulsed; $t_{p} \le$ 300 μs; $\delta \le$ 0.02; T_{amb} = 25 °C	325	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = 1 A; I_B = 10 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	55	mV



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	
2	Е	emitter		С
3	С	collector	Transparent top view DFN2020D-3 (SOT1061D)	B — E sym021

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PBSS4310PAS-Q	DFN2020D-3	plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); no leads; 3 terminals; 1.3 mm pitch; 2 mm x 2 mm x 0.65 mm body	SOT1061D			

7. Marking

Table 4. Marking codes

Type number	Marking code
PBSS4310PAS-Q	F2

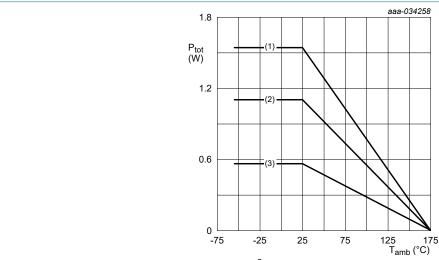
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	10	V
V_{CEO}	collector-emitter voltage	open base		-	10	V
V _{EBO}	emitter-base voltage	open collector		-	8	V
I _C	collector current			-	3	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	5	Α
I _B	base current			-	500	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	560	mW
			[2]	-	1.1	W
			[3]	-	1.54	W
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2]
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm². Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



- (1) FR4 PCB, single-sided copper, 6 $\rm cm^2$ (2) FR4 PCB, single-sided copper, 1 $\rm cm^2$
- (3) FR4 PCB, single-sided copper, standard footprint

Fig. 1. **Power derating curves**

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j-a)	thermal resistance from		[1]	-	-	268	K/W
	junction to ambient		[2]	-	-	137	K/W
			[3]	-	-	98	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	7	K/W

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

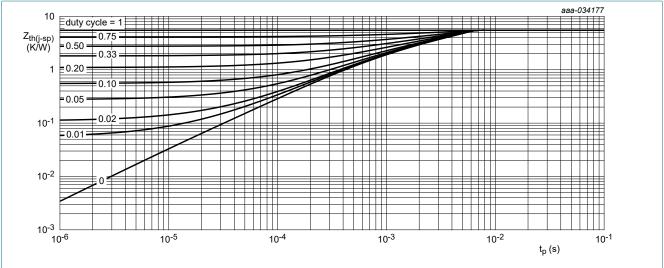


Fig. 2. Transient thermal impedance from junction to solderpoint as a function of pulse duration; typical values

10. Characteristics

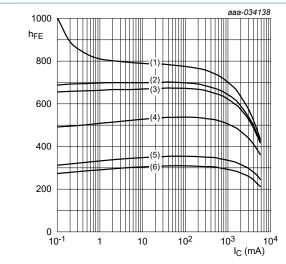
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A$	10	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = 10 \text{ mA}; I_B = 0 \text{ A}$	10	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	$I_E = 100 \ \mu A; I_C = 0 \ A$	8	-	-	V
I _{CBO} collector-base cut-off current	collector-base cut-off	V _{CB} = 8 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
	current	V _{CB} = 8 V; I _E = 0 A; T _j = 125 °C	-	-	50	μΑ
I _{CES}	collector-emitter cut-off current	V _{CE} = 8 V; V _{BE} = 0 V; T _{amb} = 25 °C	-	-	100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = 6.4 V; I _C = 0 A; T _{amb} = 25 °C	-	-	100	nA

Symbol	Parameter	Conditions	Mir	т Тур	Max	Unit
h _{FE}	DC current gain	V_{CE} = 2 V; I_{C} = 100 mA; pulsed; $t_{p} \le$ 300 μs; $\delta \le$ 0.02; T_{amb} = 25 °C	325	5 -	-	
		V_{CE} = 2 V; I_{C} = 500 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	325	5 -	-	
		V_{CE} = 2 V; I_{C} = 1 A; pulsed; $t_{p} \le 300 \ \mu s$; δ ≤ 0.02; T_{amb} = 25 °C	300) -	-	
		V_{CE} = 2 V; I_{C} = 2 A; pulsed; $t_{p} \le 300 \ \mu s$; δ ≤ 0.02; T_{amb} = 25 °C	275	5 -	-	
		V_{CE} = 2 V; I_{C} = 3 A; pulsed; $t_{p} \le 300 \ \mu s$; δ ≤ 0.02; T_{amb} = 25 °C	250) -	-	
OLSat	collector-emitter saturation voltage	I_C = 500 mA; I_B = 50 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.02; T_{amb} = 25 °C	-	-	25	mV
		I_C = 1 A; I_B = 50 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	35	mV
		I_C = 1 A; I_B = 10 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	55	mV
		I_C = 2 A; I_B = 20 mA; pulsed; $t_p \le$ 300 µs; $\delta \le$ 0.02; T_{amb} = 25 °C	-	-	85	mV
		I_C = 3 A; I_B = 150 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	90	mV
		I_C = 3 A; I_B = 30 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	110	mV
V_{BEsat}	base-emitter saturation voltage	I_C = 1 A; I_B = 100 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	1	V
		I_C = 3 A; I_B = 300 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	1.2	V
V_{BEon}	base-emitter turn-on voltage	V_{CE} = 2 V; I_{C} = 2 A; pulsed; $t_{p} \le 300 \ \mu s$; δ ≤ 0.02; T_{amb} = 25 °C	-	-	845	mV
t _d	delay time	I _C = 2 A; I _{Bon} = 100 mA; I _{Boff} = -100 mA;	-	16	-	ns
t _r	rise time	T _{amb} = 25 °C	-	55	-	ns
t _s	storage time		-	190	-	ns
t _f	fall time		-	48	-	ns
f _⊤	transition frequency	V_{CE} = 5 V; I_{C} = 100 mA; f = 100 MHz; T_{amb} = 25 °C	-	80	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 ^{\circ}\text{C}$	-	75	-	pF

aaa-034139

10 V, 3 A NPN low VCEsat transistor



 $V_{CE} = 5 V$ (1) $T_{amb} = 150 °C$

(2) $T_{amb} = 100 \, ^{\circ}C$

 $(3) T_{amb} = 85 °C$

(4) $T_{amb} = 25 \, ^{\circ}C$

(5) T_{amb} = -40 °C (6) T_{amb} = -55 °C

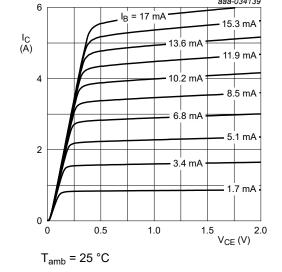
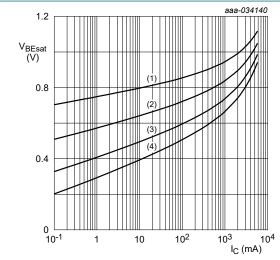


Fig. 4. Collector current as a function of collectoremitter voltage; typical values





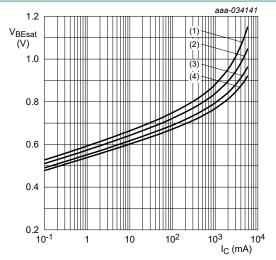
 $I_{\rm C}/I_{\rm B}=20$

(1) $T_{amb} = -55$ °C

(2) T_{amb} = 25 °C

(3) T_{amb} = 100 °C (4) T_{amb} = 150 °C

Fig. 5. Base-emitter saturation voltage as a function of Fig. 6. collector current; typical values



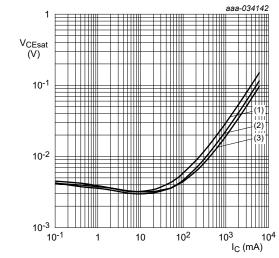
 T_{amb} = 25 °C

 $(1) I_{\rm C}/I_{\rm B} = 10$

(2) $I_C/I_B = 20$

(3) $I_C/I_B = 50$ $(4) I_C/I_B = 100$

Base-emitter saturation voltage as a function of collector current; typical values

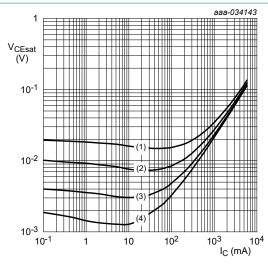


 $I_C/I_B = 20$ (1) $T_{amb} = 125 \,^{\circ}C$

(2) T_{amb} = 25 °C

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values

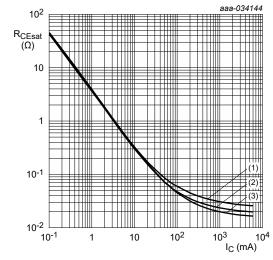


 $T_{amb} = 25 \, ^{\circ}C$ (1) $I_{C}/I_{B} = 100$

(2) $I_C/I_B = 50$

 $(3) I_{\rm C}/I_{\rm B} = 20$ $(4) I_{\rm C}/I_{\rm B} = 10$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

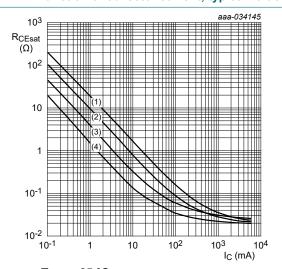


 $I_{\rm C}/I_{\rm B}=20$

(1) $T_{amb} = 125 \, ^{\circ}C$

(2) T_{amb} = 25 °C (3) T_{amb} = -40 °C

Fig. 9. Collector-emitter saturation resistance as a function of collector current; typical values

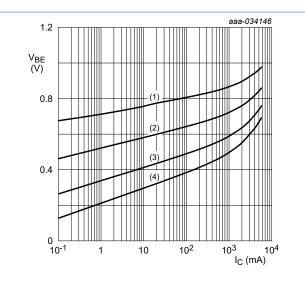


 T_{amb} = 25 °C $(1) I_{\rm C}/I_{\rm B} = 100$

(2) $I_C/I_B = 50$

(3) $I_C/I_B = 20$ $(4) I_{C}/I_{B} = 10$

Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values

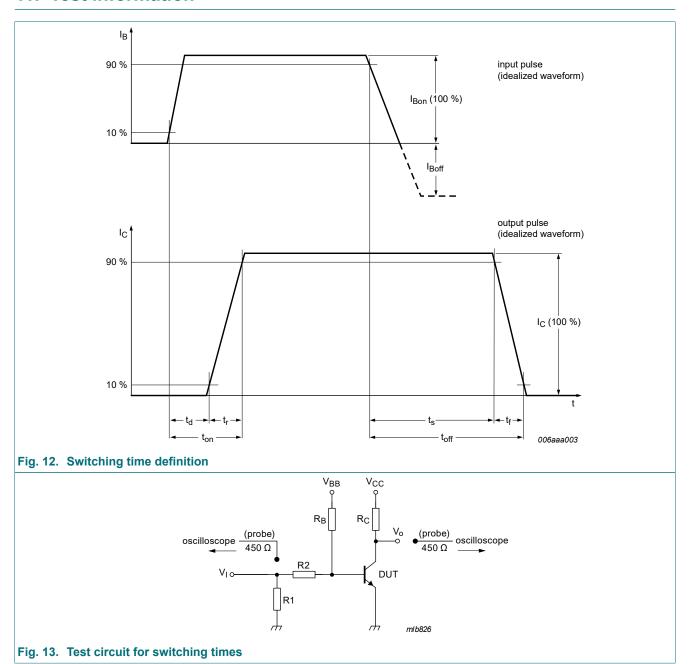


V_{CE} = 2 V (1) T_{amb} = -55 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C (4) T_{amb} = 150 °C

Fig. 11. Base-emitter voltage as a function of collector current; typical values

8 / 14

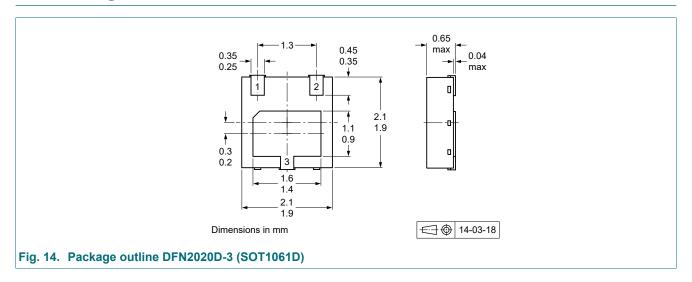
11. Test information



Quality information

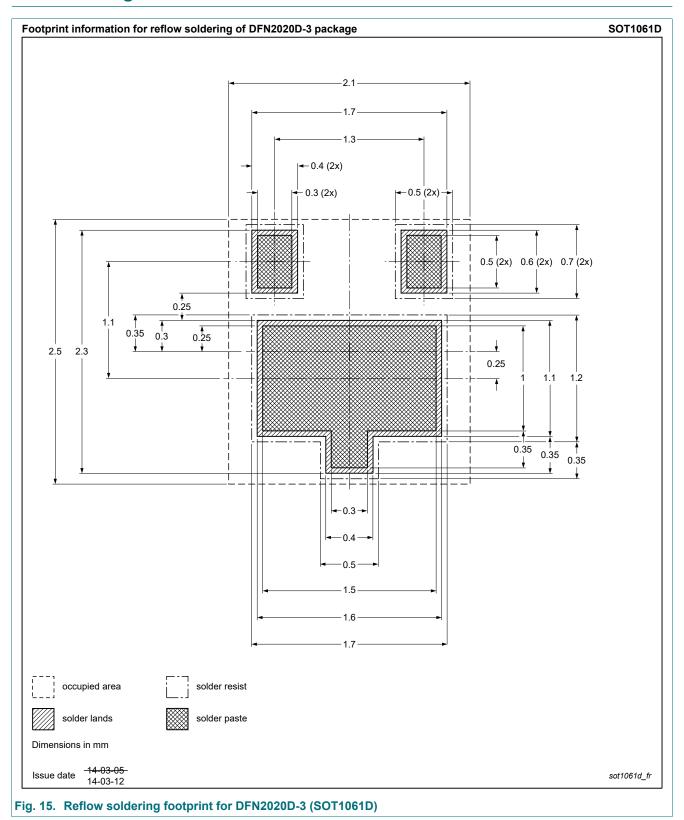
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



10 / 14

13. Soldering



14. Revision history

Table 8. Revision history

Table 6. Revision history								
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PBSS4310PAS-Q v.4	20241220	Product data sheet	-	PBSS4310PAS-Q v.3				
Modifications:	Characteristics: Grap	Characteristics: Graphs in figures 7 and 9 corrected						
PBSS4310PAS-Q v.3	20220121	Product data sheet	-	PBSS4310PAS-Q v.2				
PBSS4310PAS-Q v.2	20211215	Product data sheet	-	PBSS4310PAS-Q v.1				
PBSS4310PAS-Q v.1	20211203	Preliminary data sheet	-	-				

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	4
10	. Characteristics	4
11.	. Test information	9
12	. Package outline	10
13	. Soldering	11
	. Revision history	
	Legal information	

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